



PJN1NA60 / PJW1NA60 / PJU1NA60 / PJD1NA60

Current

1 A

600V N-Channel MOSFET

600 V

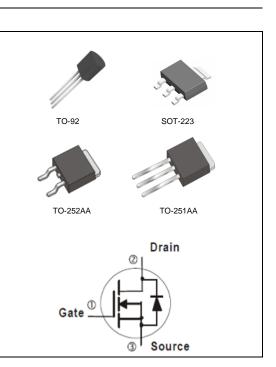
Voltage

Features

- R_{DS(ON)}, V_{GS}@10V,I_D@0.5A<14Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-251AA, TO-252AA, SOT-223, TO-92 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- SOT-223 Approx. Weight : 0.043 ounces, 0.123grams
- TO-92 Approx. Weight : 0.007 ounces, 0.196grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-252AA	SOT-223	TO-92	UNITS
Drain-Source Voltage		V _{DS}	600				V
Gate-Source Voltage		V _{GS}	<u>+</u> 30				V
Continuous Drain Current		I _D	1 0.3		.3	А	
Pulsed Drain Current		I _{DM}	4 1.2		.2	А	
Single Pulse Avalanche Energy (Note 1)		E _{AS}	50				mJ
Power Dissipation	T _c =25°C	P _D	2	7	3.3	3	W
	Derate above 25°C		0.2	216	0.026	0.024	W/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150			°C	
Typical Thermal resistance							
- Junction to Case		$R_{ extsf{ heta}JC}$	4.	63	-	-	°C/W
- Junction to Ambient		$R_{ extsf{ heta}JA}$	1 [.]	10	37.9 ^(Note 4)	140	

• Limited only By Maximum Junction Temperature





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Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	600	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	3.34	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =0.5A	-	11.1	14	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =600V,V _{GS} =0V	-	0.02	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 30V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	-	0.85	1.4	V
Dynamic (Note 5)						
Total Gate Charge	Qg		-	3.3	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =480V, I _D =1A, V _{GS} =10V ^(Note 2,3)	-	1.1	-	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	1	-	
Input Capacitance	Ciss		-	95	-	pF
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	21	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	0.3	-	
Turn-On Delay Time	td _(on)	(on)		5	-	
Turn-On Rise Time	t _r	$V_{DD}=300V, I_{D}=1A,$ $R_{G}=25\Omega^{(Note 2,3)}$	-	20	-	ns
Turn-Off Delay Time	td _(off)	$R_{G}=25\Omega$	-	8	-	
Turn-Off Fall Time	t _f		-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	1	A
Diode Forward Current	I _S					
Maximum Pulsed Drain-Source				-	4	А
Diode Forward Current	I _{SM}		-			
Reverse Recovery Time	trr	V _{GS} =0V, I _S =1A	-	190	-	ns
Reverse Recovery Charge	Qrr	dI _F / dt=100A/us ^(Note 2)	-	0.53	-	uC

NOTES :

1. L=30mH, I_{AS}=1.77A, V_{DD}=50V, R_G=25 ohm, Starting T_J=25 $^{\circ}$ C

2. Pulse width \leq 300 us, Duty cycle \leq 2%

3. Essentially independent of operating temperature typical characteristics.

4. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper

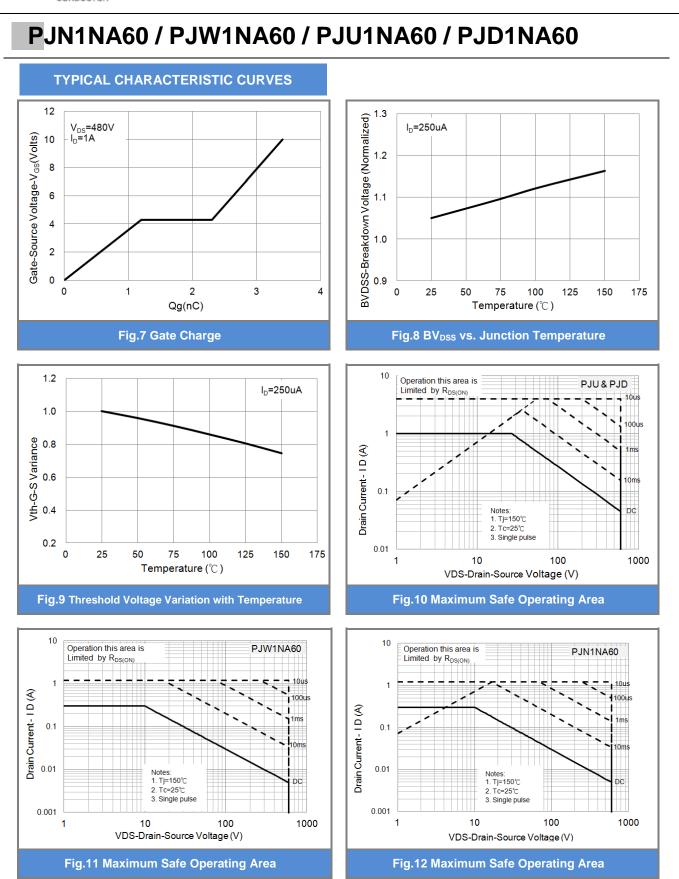
5. Guaranteed by design, not subject to production testing.





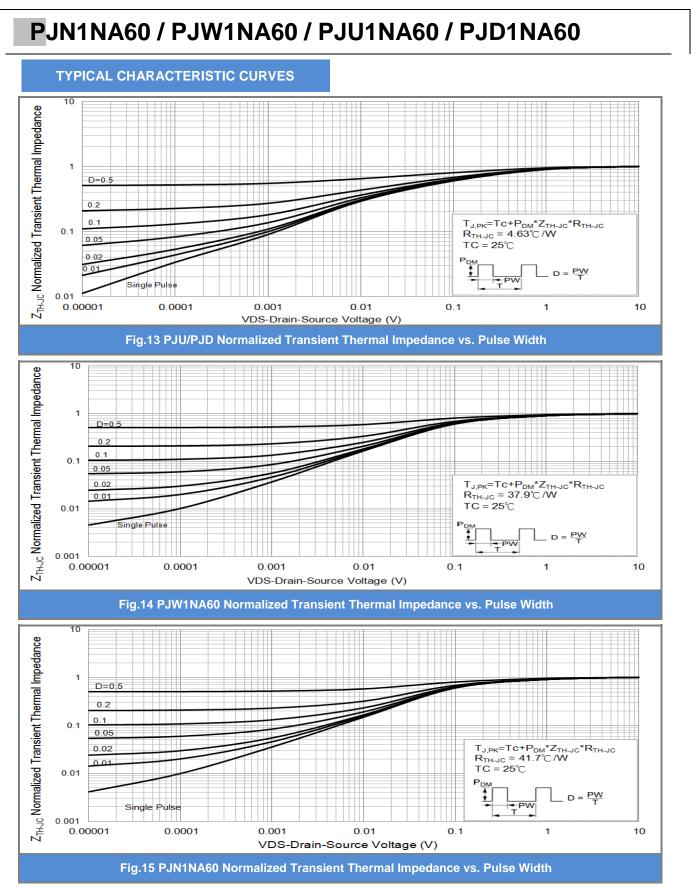
PJN1NA60 / PJW1NA60 / PJU1NA60 / PJD1NA60 **TYPICAL CHARACTERISTIC CURVES** 1.2 1.5 V_{DS}=50V V_{GS}=10V V_{GS}=8V I_{Ds}-Drain-to-Source Current(A) I_{DS}-Drain-to-S ource Current(A) 1.2 0.9 0.6 V_{GS}=5V 0.3 T_=25 T_=125℃ V_{GS}=4.5V 0.0 0 10 20 30 40 50 0 2 6 8 10 4 VDS- Drain-to-Source Voltage(V) VGS-Gate-to-Source Voltage(V) **Fig.1 Output Characteristics Fig.2 Transfer Characteristics** 15 3.0 V_{GS}= 10V V_{GS}=10V, I_D=0.5A R_{DS}(on)- On-Resistance (Normalized) 14 2.5 $R_{DS}(on)$ - On-Resistance(Ω) 13 2.0 1.5 12 1.0 11 10 0.5 9 0.0 0.0 0.2 0.4 0.6 0.8 1.0 0 25 50 75 100 125 150 175 Temperature (℃) IDS-Drain-to-Source Current(A) Fig.3 On-Resistance vs. Drain Current Fig.4 On-Resistance vs. Junction Temperature 1000 10 Ciss Is-Source to-Drain Current(A) 100 1 Capacitance (pF) Coss 0.1 10 0.01 1 T_i=125℃ T_i=25℃ Crss V_{GS}=0V f=1MHz 0.001 0.1 0 0.3 0.6 0.9 1.2 1.5 0.1 10 100 1 VDS-Drain-Source Voltage (V) VSD-Source-to-Drain Voltage(V) Fig.5 Capacitance vs. Drain-Source Voltage Fig.6 Source-Drain Diode Forward Voltage







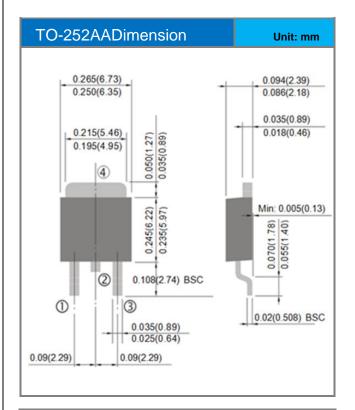


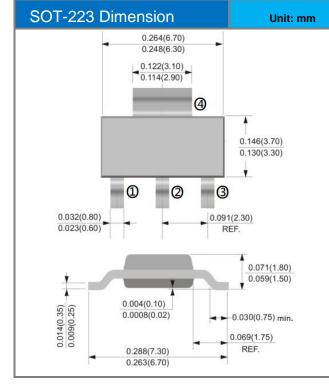


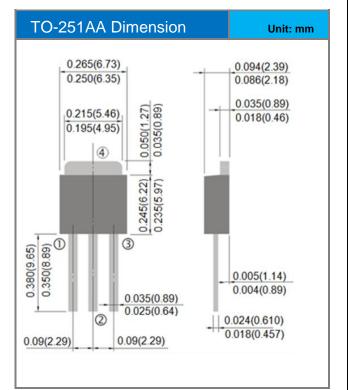


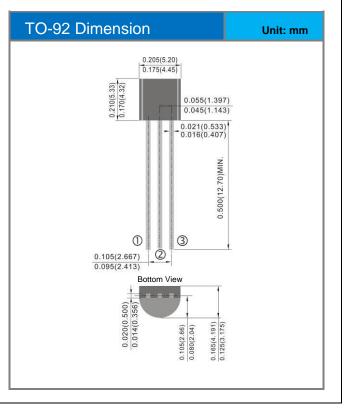


Packaging Information













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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJU1NA60_T0_00001	TO-251AA	80pcs / Tube	U1NA60	Halogen free
PJD1NA60_L2_00001	TO-252AA	3,000pcs / 13" reel	D1NA60	Halogen free
PJW1NA60_R2_00001	SOT-223	2,500pcs / 13" reel	1NA60	Halogen free
PJN1NA60_B0_00001	TO-92	1000pcs / bag	1NA60	Halogen free
PJN1NA60_A0_00001	TO-92 AMMO	2000pcs / box	1NA60	Halogen free





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